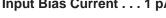
TLV2370, TLV2371, TLV2372, TLV2373, TLV2374, TLV2375 FAMILY OF 550-µA/Ch 3-MHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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Operational Amplifier

- Rail-To-Rail Input/Output
- Wide Bandwidth . . . 3 MHz
- High Slew Rate . . . 2.4 V/μs
- Supply Voltage Range . . . 2.7 V to 16 V
- Supply Current . . . 550 μA/Channel
- Low Power Shutdown Mode I_{DD(SHDN)} . . . 25 μA/Channel
- Input Noise Voltage . . . 39 nV/√Hz
- Input Bias Current . . . 1 pA
- **Specified Temperature Range** -40°C to 125°C . . . Industrial Grade
- Ultrasmall Packaging
 - 5 or 6 Pin SOT-23 (TLV2370/1)



8 or 10 Pin MSOP (TLV2372/3)

description

The TLV237x single supply operational amplifiers provide rail-to-rail input and output capability. The TLV237x takes the minimum operating supply voltage down to 2.7 V over the extended industrial temperature range while adding the rail-to-rail output swing feature. The TLV237x also provides 3-MHz bandwidth from only 550 μA. The maximum recommended supply voltage is 16 V, which allows the devices to be operated from (±8 V supplies down to ± 1.35 V) a variety of rechargeable cells.

The CMOS inputs enable use in high-impedance sensor interfaces, with the lower voltage operation making an ideal alternative for the TLC227x in battery-powered applications. The rail-to-rail input stage further increases its versatility. The TLV237x is the seventh member of a rapidly growing number of RRIO products available from TI, and it is the first to allow operation up to 16-V rails with good ac performance.

All members are available in PDIP and SOIC with the singles in the small SOT-23 package, duals in the MSOP, and quads in the TSSOP package.

The 2.7-V operation makes the TLV237x compatible with Li-lon powered systems and the operating supply voltage range of many micro-power microcontrollers available today including Tl's MSP430.

SELECTION OF SIGNAL AMPLIFIER PRODUCTST

DEVICE	V _{DD} (V)	V _{IO} (μV)	lq/Ch (μA)	I _{IB} (pA)	GBW (MHz)	SR (V/μs)	SHUTDOWN	RAIL- TO- RAIL	SINGLES/DUALS/QUADS
TLV237x	2.7–16	500	550	1	3	2.4	Yes	I/O	S/D/Q
TLC227x	4–16	300	1100	1	2.2	3.6	_	0	D/Q
TLV27x	2.7–16	500	550	1	3	2.4	_	0	S/D/Q
TLC27x	3–16	1100	675	1	1.7	3.6	_	_	S/D/Q
TLV246x	2.7–6	150	550	1300	6.4	1.6	Yes	I/O	S/D/Q
TLV247x	2.7–6	250	600	2	2.8	1.5	Yes	I/O	S/D/Q
TLV244x	2.7–10	300	725	1	1.8	1.4	_	0	D/Q

[†] Typical values measured at 5 V, 25°C



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



TLV2370, TLV2371, TLV2372, TLV2373, TLV2374, TLV2375 FAMILY OF 550-µA/Ch 3-MHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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FAMILY PACKAGE TABLE

DEV//OF	NUMBER OF		PAC	KAGE TY	PES		OLULTDOWN.	UNIVERSAL	
DEVICE	CHANNELS	PDIP	SOIC	SOT-23	TSSOP	MSOP	SHUTDOWN	EVM BOARD	
TLV2370	1	8	8	6	_	_	Yes		
TLV2371	1	8	8	5	_	_	_		
TLV2372	2	8	8	_	_	8	_	Refer to the EVM	
TLV2373	2	14	14	_	_	10	Yes	Selection Guide (Lit# SLOU060)	
TLV2374	4	14	14	_	14	_	_	(
TLV2375	4	16	16	_	16	_	Yes		

TLV2370 and TLV2371 AVAILABLE OPTIONS

	.,,		PACKAGED D	EVICES	
TA	V _{IO} MAX AT 25°C	SMALL OUTLINE	SOT-23	PLASTIC DIP	
	25 0	(D) [†]	(DBV)‡	SYMBOL	(P)
-40°C to 125°C	4.5 mV	TLV2370ID TLV2371ID	TLV2370IDBV TLV2371IDBV	VBFI VBGI	TLV2370IP TLV2371IP

[†] This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2370IDR).

TLV2372 AND TLV2373 AVAILABLE OPTIONS

				PAC	KAGED DEVICES	3		
TA	V _{IO} MAX AT 25°C	SMALL	MSOP				PLASTIC	PLASTIC
	25 0	OUTLINE (D)§	(DGK)§	SYMBOL	(DGS)§	SYMBOL	DIP (N)	DIP (P)
-40°C to 125°C	4.5 mV	TLV2372ID TLV2373ID	TLV2372IDGK —	APG —	 TLV2373IDGS	— API	 TLV2373IN	TLV2372IP —

[§] This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2372IDR).

TLV2374 and TLV2375 AVAILABLE OPTIONS

	V 144V AT	PACK	AGED DEVICES	
TA	V _{IO} MAX AT 25°C	SMALL OUTLINE (D)¶	PLASTIC DIP (N)	TSSOP (PW)¶
-40°C to 125°C	4.5 mV	TLV2374ID TLV2375ID	TLV2374IN TLV2375IN	TLV2374IPW TLV2375IPW

This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2374IDR).

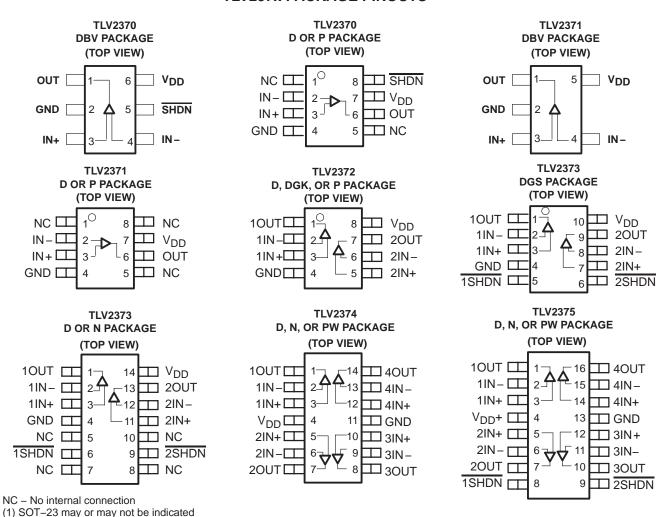


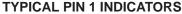
[‡] This package is only available taped and reeled. For standard quantities (3,000 pieces per reel), add an R suffix (e.g., TLV2370IDBVR). For smaller quantities (250 pieces per mini-reel), add a T suffix to the part number (e.g., TLV2370IDBVT).

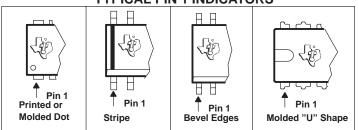
TLV2370, TLV2371, TLV2372, TLV2373, TLV2374, TLV2375 FAMILY OF 550-µA/Ch 3-MHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TLV237x PACKAGE PINOUTS(1)







TLV2370, TLV2371, TLV2372, TLV2373, TLV2374, TLV2375 FAMILY OF 550-µA/Ch 3-MHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{DD} (see Note 1)	
Differential input voltage, V _{ID}	
Input voltage range, V _I (see Note 1)	
Input current range, I ₁	±10 mA
Output current range, IO	±100 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A : I suffix	–40°C to 125°C
Maximum junction temperature, T _J	150°C
Maximum junction temperature, T _J	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential voltages, are with respect to GND.

DISSIPATION RATING TABLE

PACKAGE	θJC	θJA (°C/W)	T _A ≤ 25°C POWER RATING
D (8)	38.3	176	710 mW
D (14)	26.9	122.3	1022 mW
D (16)	25.7	114.7	1090 mW
DBV (5)	55	324.1	385 mW
DBV (6)	55	294.3	425 mW
DGK (8)	54.23	259.96	481 mW
DGS (10)	54.1	257.71	485 mW
N (14, 16)	32	78	1600 mW
P (8)	41	104	1200 mW
PW (14)	29.3	173.6	720 mW
PW (16)	28.7	161.4	774 mW

recommended operating conditions

		MIN	MAX	UNIT	
	Single supply	2.7	16		
Supply voltage, V _{DD}	Split supply	±1.35	±8	V	
Common-mode input voltage range, VICR		0	V_{DD}	V	
Operating free-air temperature, T _A	I-suffix	-40	125	°C	
Turnon voltage level, V _(ON) , relative to GND pin voltaç	ge		2		
Turnoff voltage level, V(OFF), relative to GND pin volta	urnoff voltage level, V _(OFF) , relative to GND pin voltage			V	

TLV2370, TLV2371, TLV2372, TLV2373, TLV2374, TLV2375 FAMILY OF 550-µA/Ch 3-MHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN SLOS270C - MARCH 2001 - REVISED DECEMBER 2003

electrical characteristics at specified free-air temperature, V_{DD} = 2.7 V, 5 V, and 15 V (unless otherwise noted)

dc performance

	PARAMETER	TEST CONDI	TIONS	TA	MIN	TYP	MAX	UNIT
\/	lanut offeet voltage	V V /0	., ., .,	25°C		2	4.5	mV
VIO	Input offset voltage	$V_{IC} = V_{DD}/2,$ $R_S = 50 \Omega$	$V_O = V_{DD}/2$,	Full range			6	mv
ανιο	Offset voltage drift	11.3 - 00 22		25°C		2		μV/°C
		$V_{IC} = 0$ to V_{DD} ,		25°C	50	68		
		$R_S = 50 \Omega$	\/ 27\/	Full range	49			
		V_{IC} = 0 to V_{DD} -1.35V, R_S = 50 Ω	$V_{DD} = 2.7 V$	25°C	56	70		
				Full range	54			dB
		$V_{IC} = 0$ to V_{DD} ,		25°C	55	72		
CMRR	Common mode rejection retio	$R_S = 50 \Omega$,	\/ 5 \/	Full range	54			
CMRR	Common-mode rejection ratio	$V_{IC} = 0$ to $V_{DD} - 1.35V$,	$V_{DD} = 5 V$	25°C	67	80		
		$R_S = 50 \Omega$,		Full range	64			
		$V_{IC} = 0 \text{ to } V_{DD},$ $R_S = 50 \Omega,$	\	25°C	64	82		
				Full range	63			
		$V_{IC} = 0 \text{ to } V_{DD} - 1.35V,$	V _{DD} = 15 V	25°C	67	84		
		$R_S = 50 \Omega$,		Full range	66			
			\/ 0.7\/	25°C	98	106		
			$V_{DD} = 2.7 V$	Full range	76			dB
Δ	Large-signal differential voltage	$V_{O(PP)} = V_{DD}/2$.,	25°C	100	110		
AVD	amplification	$R_L = 10 \text{ k}\Omega$	$V_{DD} = 5 V$	Full range	86			
				25°C	81	83		
			$V_{DD} = 15 V$	Full range	79			

input characteristics

	PARAMETER	TEST	CONDITIONS	TA	MIN	TYP	MAX	UNIT
				25°C		1	60	pА
IIO	Input offset current			70°C			100	
		V _{DD} = 15 V,	$V_{IC} = V_{DD}/2$,	125°C			1000	
		$V_{DD} = 15 \text{ V},$ $V_{O} = V_{DD}/2$		25°C		1	60	
I _{IB}	Input bias current			70°C			100	pA
				125°C			1 60 100 1000 1 60 1000 1000	
r _{i(d)}	Differential input resistance			25°C		1000		$G\Omega$
CIC	Common-mode input capacitance	f = 21 kHz		25°C		8		pF

TLV2370, TLV2371, TLV2372, TLV2373, TLV2374, TLV2375 FAMILY OF 550- μ A/Ch 3-MHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN SLOS270C - MARCH 2001 - REVISED DECEMBER 2003

electrical characteristics at specified free-air temperature, $V_{\mbox{DD}}$ = 2.7 V, 5 V, and 15 V (unless otherwise noted) (continued)

output characteristics

	PARAMETER	TEST CONDITIONS		TA	MIN	TYP	MAX	UNIT
				25°C	2.55	2.58		
			$V_{DD} = 2.7 V$	Full range	2.48			
			.,	25°C	4.9	4.93		
		$V_{IC} = V_{DD}/2$, $I_{OH} = -1 \text{ mA}$	$V_{DD} = 5 V$	Full range	4.85			
			V 45.V	25°C	14.92	14.96		
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	High lovel output voltage		$V_{DD} = 15 V$	Full range	14.9			V
VOH	High-level output voltage		V 27V	25°C	1.9	2		V
			$V_{DD} = 2.7 V$	Full range	1.6			
		\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	V _{DD} = 5 V	25°C	4.6	4.68		
		$V_{IC} = V_{DD}/2$, $I_{OH} = -5 \text{ mA}$		Full range	4.5			
			V 15 V	25°C	14.7	14.8		
			$V_{DD} = 15 V$	Full range	14.6			
			V== - 27V	25°C		0.1	0.15	V
			V _{DD} = 2.7 V	Full range			0.22	
		$V_{IC} = V_{DD}/2$, $I_{OL} = 1 \text{ mA}$	V _{DD} = 5 V	25°C		0.05	0.1	
			ΔDD = 2 Δ	Full range			0.15	
			V _{DD} = 15 V	25°C		0.05	0.08	
VOL	Low-level output voltage			Full range			0.1	
VOL	Low-level output voltage		V _{DD} = 2.7 V	25°C		0.52	0.7	
				Full range			1.1	
		$V_{IC} = V_{DD}/2$, $I_{OL} = 5 \text{ mA}$	V _{DD} = 5 V	25°C		0.28	0.4	
		v C = vDD/2, OL = 3 IIIA	√DD = 3 √	Full range			0.5	
			V _{DD} = 15 V	25°C		0.19	0.3	
			VDD = 13 V	Full range			0.35	
		$V_{DD} = 2.7 \text{ V}, V_{O} = 0.5 \text{ V from rail}$	Positive rail	25°C		4		- mA
		VDD = 2.7 V, VO = 0.3 V Hom fall	Negative rail	25°C		5		
	Output oursent	\\ \ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\	Positive rail	25°C		7		
10	Output current	$V_{DD} = 5 \text{ V}, V_{O} = 0.5 \text{ V from rail}$	Negative rail	25°C		8		
		V 45V V 05V "	Positive rail	25°C		16		
		$V_{DD} = 15 \text{ V}, V_O = 0.5 \text{ V from rail}$	Negative rail	25°C		15		

power supply

PARAMETER		TEST COND	TA	MIN	TYP	MAX	UNIT	
I _{DD} Suppl			V _{DD} = 2.7 V	25°C		470	560	60 00 μΑ
	Cumply current (nor channel)	$V_O = V_{DD}/2$,	V _{DD} = 5 V	25°C		550	660	
	Supply current (per channel)		V 45.V	25°C		750	900	
			V _{DD} = 15 V	Full range			1200	
PSRR	Supply voltage rejection ratio	$V_{DD} = 2.7 \text{ V to } 15 \text{ V},$	$V_{IC} = V_{DD}/2$,	25°C	70	80		-ID
	$(\Delta V_{DD} / \Delta V_{IO})$	No load		Full range	65			dB

TLV2370, TLV2371, TLV2372, TLV2373, TLV2374, TLV2375 FAMILY OF 550-μA/Ch 3-MHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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electrical characteristics at specified free-air temperature, V_{DD} = 2.7 V, 5 V, and 15 V (unless otherwise noted) (continued)

dynamic performance

PARAMETER		TEST CONDITIONS		TA	MIN	TYP	MAX	UNIT
UGBW	Unity gain bandwidth	$R_L = 2 k\Omega$, $C_L = 10 pF$	V _{DD} = 2.7 V	25°C		2.4		MHz
			V _{DD} = 5 V to 15 V	25°C		3		
	Slew rate at unity gain	$V_{O(PP)} = V_{DD}/2,$ $C_{L} = 50 \text{ pF},$ $R_{L} = 10 \text{ k}\Omega$	V _{DD} = 2.7 V	25°C	1.4	2		V/μs
				Full range	1			
SR			V _{DD} = 5 V	25°C	1.6	2.4		V/μs
				Full range	1.2			
			V _{DD} = 15 V	25°C	1.9	2.1		V/μs
				Full range	1.4			
φm	Phase margin	$R_L = 2 k\Omega$,	C _L = 100 pF	25°C		65°		
	Gain margin	$R_L = 2 k\Omega$,	C _L = 10 pF	25°C		18		dB
t _S	Settling time	$V_{DD} = 2.7 \text{ V},$ $V_{(STEP)PP} = 1 \text{ V}, A_{V} = -1,$ $C_{L} = 10 \text{ pF}, R_{L} = 2 \text{ k}\Omega$	0.1%	25°C —		2.9		μs
		$\begin{split} V_{DD} &= 5 \text{ V}, \ 15 \text{ V}, \\ V_{(STEP)PP} &= 1 \text{ V}, A_{V} = -1, \\ C_{L} &= 47 \text{ pF}, \qquad \qquad R_{L} = 2 \text{ k}\Omega \end{split}$	0.1%			2		

noise/distortion performance

PARAMETER		TEST CONDITIONS		TA	MIN	TYP	MAX	UNIT		
THD + N	Total harmonic distortion plus noise	$V_{DD} = 2.7 \text{ V},$ $V_{O(PP)} = V_{DD}/2 \text{ V},$ $R_{L} = 2 \text{ k}\Omega, \text{ f} = 10 \text{ kHz}$	A _V = 1	25°C		0.02%				
			Ay = 10			0.05%				
			Ay = 100			0.18%]		
		$V_{DD} = 5 \text{ V}, 15 \text{ V},$ $V_{O(PP)} = V_{DD}/2 \text{ V},$ $R_L = 2 \text{ k}\Omega, f = 10 \text{ kHz}$	Ay = 1	25°C		0.02%				
			Ay = 10			0.09%				
			A _V = 100			0.5%				
.,		f = 1 kHz				39		nV/√ Hz		
V _n	Equivalent input noise voltage	f = 10 kHz		25°C		35				
In	Equivalent input noise current	f = 1 kHz		25°C		0.6		fA/√Hz		

shutdown characteristics

PARAMETER		TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
	Supply current in shutdown mode (TLV2370,	<u>V_{DD}</u> = 2.7 V, 5 V, SHDN = 0 V	25°C		25	30	μА
I _{DD(SHDN)}			Full range			35	
		<u>V_{DD} =</u> 15 V, SHDN = 0 V	25°C		40	45	•
			Full range			50	μА
t(on)	Amplifier turnon time (see Note 2)	D. O.LO	25°C		0.8		μs
t(off)	Amplifier turnoff time (see Note 2)	$R_L = 2 k\Omega$	25°C		1		μs

NOTE 2: Disable time and enable time are defined as the interval between application of the logic signal to the SHDN terminal and the point at which the supply current has reached one half of its final value.



TLV2370, TLV2371, TLV2372, TLV2373, TLV2374, TLV2375 FAMILY OF 550-µA/Ch 3-MHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN SLOS270C - MARCH 2001 - REVISED DECEMBER 2003

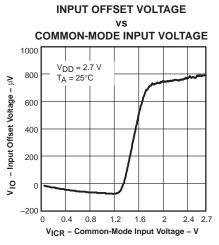
TYPICAL CHARACTERISTICS

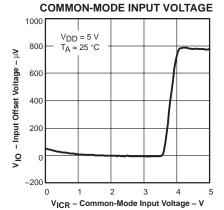
Table of Graphs

			FIGURE
V _{IO}	Input offset voltage	vs Common-mode input voltage	1, 2, 3
CMRR	Common-mode rejection ratio	vs Frequency	4
	Input bias and offset current	vs Free-air temperature	5
VOL	Low-level output voltage	vs Low-level output current	6, 8, 10
Voн	High-level output voltage	vs High-level output current	7, 9, 11
VO(PP)	Peak-to-peak output voltage	vs Frequency	12
I _{DD}	Supply current	vs Supply voltage	13
PSRR	Power supply rejection ratio	vs Frequency	14
A _{VD}	Differential voltage gain & phase	vs Frequency	15
	Gain-bandwidth product	vs Free-air temperature	16
0.0		vs Supply voltage	17
SR	Slew rate	vs Free-air temperature	18
φm	Phase margin	vs Capacitive load	19
V _n	Equivalent input noise voltage	vs Frequency	20
	Voltage-follower large-signal pulse response		21, 22
	Voltage-follower small-signal pulse response		23
	Inverting large-signal response		24, 25
	Inverting small-signal response		26
	Crosstalk	vs Frequency	27
	Shutdown forward & reverse isolation	vs Frequency	28
I _{DD} (SHDN)	Shutdown supply current	vs Supply voltage	29
IDD(SHDN)	Shutdown pin leakage current	vs Shutdown pin voltage	30
IDD(SHDN)	Shutdown supply current/output voltage	vs Time	31, 32

TYPICAL CHARACTERISTICS

INPUT OFFSET VOLTAGE





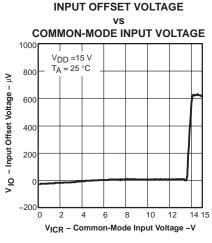
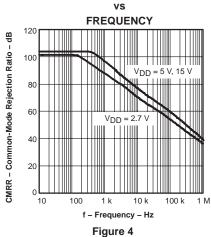


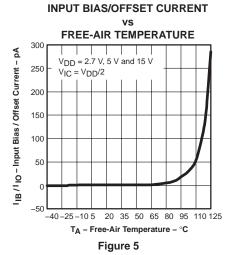
Figure 1

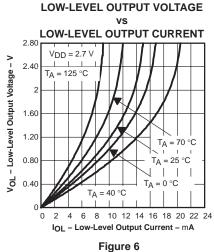
Figure 2

Figure 3

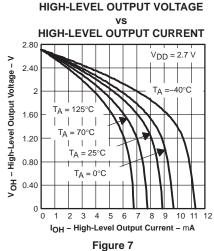
COMMON-MODE REJECTION RATIO

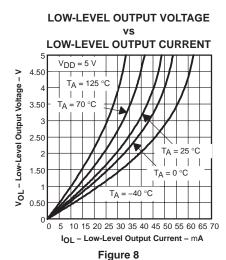






LEVEL CUITBUT VOLTAGE

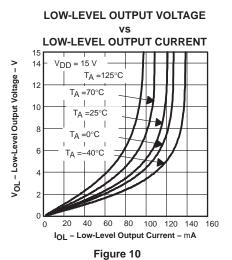


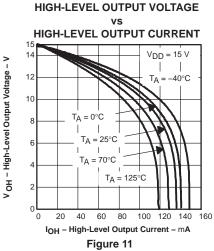


HIGH-LEVEL OUTPUT VOLTAGE HIGH-LEVEL OUTPUT CURRENT $V_{CC} = 5 V$ VOH - High-Level Output Voltage - V $T_A = -40^{\circ}C$ $T_A = 0^{\circ}C$ 3.50 2.50 $T_A = 25^{\circ}C$ T_A = 70°C $T_A = 125^{\circ}C$ 0.50 15 20 25 30 35 40 IOH - High-Level Output Current - mA

Figure 9

TYPICAL CHARACTERISTICS





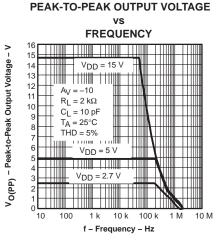


Figure 12

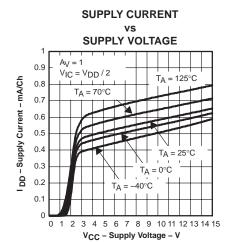


Figure 13

POWER SUPPLY REJECTION RATIO

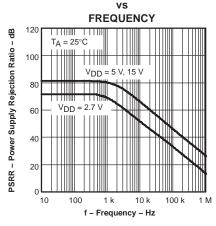
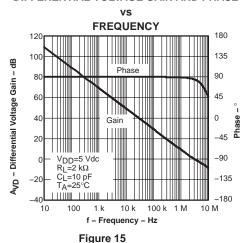


Figure 14

DIFFERENTIAL VOLTAGE GAIN AND PHASE



GAIN BANDWIDTH PRODUCT

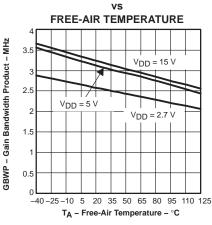
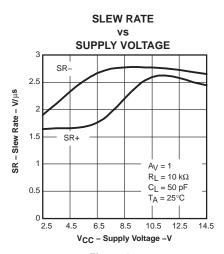
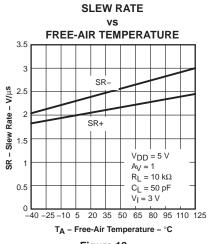


Figure 16



TYPICAL CHARACTERISTICS





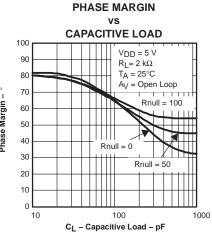


Figure 17

Figure 18

Figure 19

EQUIVALENT INPUT NOISE VOLTAGE

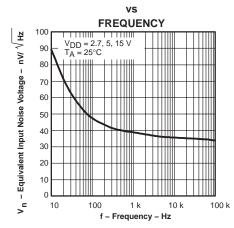


Figure 20



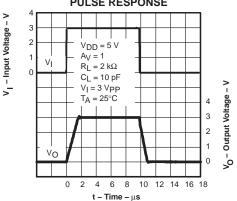


Figure 21

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

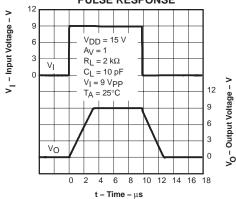


Figure 22

VOLTAGE-FOLLOWER SMALL-SIGNAL

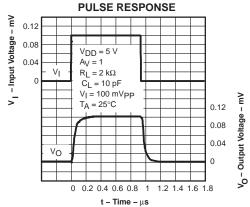


Figure 23



TLV2370, TLV2371, TLV2372, TLV2373, TLV2374, TLV2375 FAMILY OF 550-µA/Ch 3-MHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

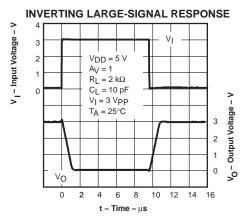


Figure 24

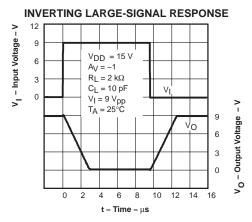


Figure 25

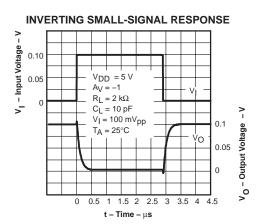


Figure 26

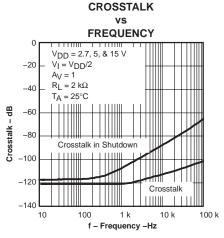
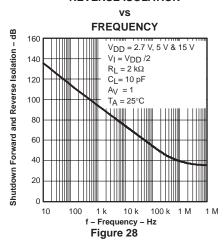
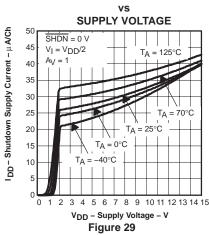


Figure 27

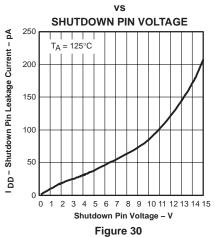
SHUTDOWN FORWARD AND REVERSE ISOLATION



SHUTDOWN SUPPLY CURRENT

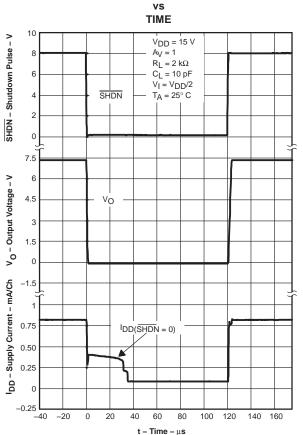


SHUTDOWN PIN LEAKAGE CURRENT



TYPICAL CHARACTERISTICS

SHUTDOWN SUPPLY CURRENT/OUTPUT VOLTAGE



SHUTDOWN SUPPLY CURRENT/OUTPUT VOLTAGE

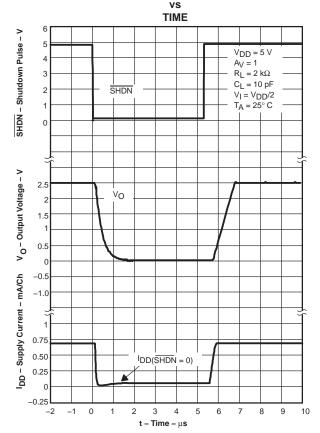


Figure 31 Figure 32

APPLICATION INFORMATION

rail-to-rail input operation

The TLV237x input stage consists of two differential transistor pairs, NMOS and PMOS, that operate together to achieve rail-to-rail input operation. The transition point between these two pairs can be seen in Figures 1, 2, and 3 for a 2.7-V, 5-V, and 15-V supply. As the common-mode input voltage approaches the positive supply rail, the input pair switches from the PMOS differential pair to the NMOS differential pair. This transition occurs approximately 1.35 V from the positive rail and results in a change in offset voltage due to different device characteristics between the NMOS and PMOS pairs. If the input signal to the device is large enough to swing between both rails, this transition results in a reduction in common-mode rejection ratio (CMRR). If the input signal does not swing between both rails, it is best to bias the signal in the region where only one input pair is active. This is the region in Figures 1 through 3 where the offset voltage varies slightly across the input range and optimal CMRR can be achieved. This has the greatest impact when operating from a 2.7-V supply voltage.

driving a capacitive load

When the amplifier is configured in this manner, capacitive loading directly on the output decreases the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 33. A minimum value of 20 Ω should work well for most applications.

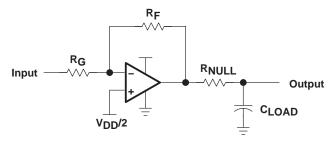


Figure 33. Driving a Capacitive Load

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

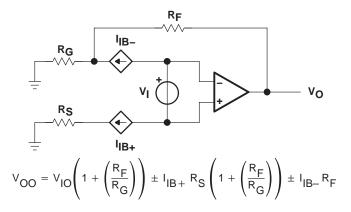


Figure 34. Output Offset Voltage Model



APPLICATION INFORMATION

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 35).

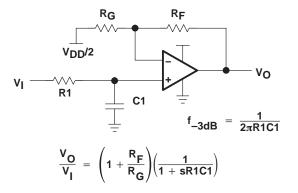


Figure 35. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

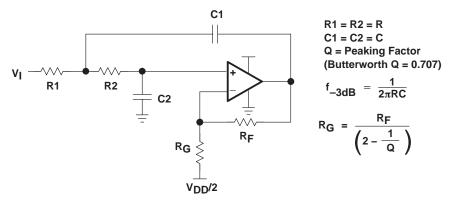


Figure 36. 2-Pole Low-Pass Sallen-Key Filter

TLV2370, TLV2371, TLV2372, TLV2373, TLV2374, TLV2375 FAMILY OF 550-µA/Ch 3-MHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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APPLICATION INFORMATION

circuit layout considerations

To achieve the levels of high performance of the TLV237x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes—It is highly recommended that a ground plane be used on the board to provide all
 components with a low inductive ground connection. However, in the areas of the amplifier inputs and
 output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling—Use a 6.8-μF tantalum capacitor in parallel with a 0.1-μF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1-μF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1-μF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets—Sockets can be used but are not recommended. The additional lead inductance in the socket pins
 will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board
 is the best implementation.
- Short trace runs/compact part placements—Optimum high performance is achieved when stray series
 inductance has been minimized. To realize this, the circuit layout should be made as compact as possible,
 thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of
 the amplifier. Its length should be kept as short as possible. This helps to minimize stray capacitance at the
 input of the amplifier.
- Surface-mount passive components—Using surface-mount passive components is recommended for high
 performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of
 surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small
 size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray
 inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be
 kept as short as possible.

shutdown function

Three members of the TLV237x family (TLV2370/3/5) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 25 μ A/channel, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care should be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown.



APPLICATION INFORMATION

general power dissipation considerations

For a given θ_{JA} , the maximum power dissipation is shown in Figure 37 and is calculated by the following formula:

$$P_{D} = \left(\frac{T_{MAX} - T_{A}}{\theta_{JA}}\right)$$

Where:

 P_D = Maximum power dissipation of TLV237x IC (watts)

T_{MAX} = Absolute maximum junction temperature (150°C)

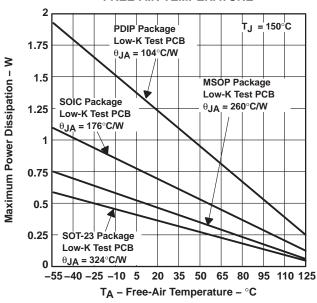
 T_A = Free-ambient air temperature (°C)

 $\theta_{JA} = \theta_{JC} + \theta_{CA}$

 θ_{JC} = Thermal coefficient from junction to case

 θ_{CA} = Thermal coefficient from case to ambient air (°C/W)

MAXIMUM POWER DISSIPATION vs FREE-AIR TEMPERATURE

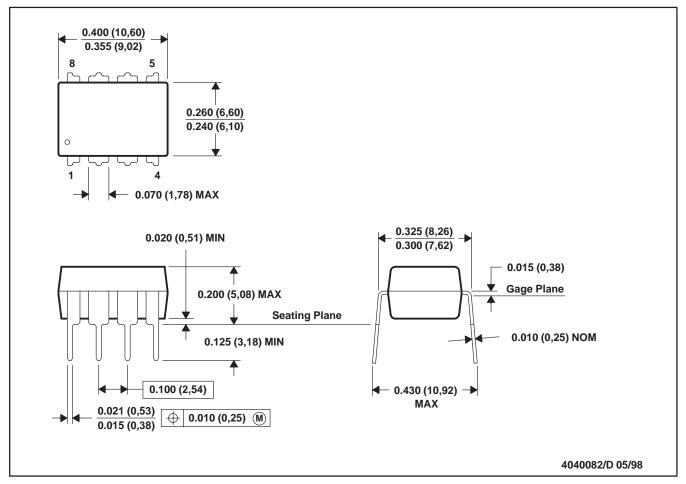


NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 37. Maximum Power Dissipation vs Free-Air Temperature

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001

For the latest package information, go to $http://www.ti.com/sc/docs/package/pkg_info.htm$

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

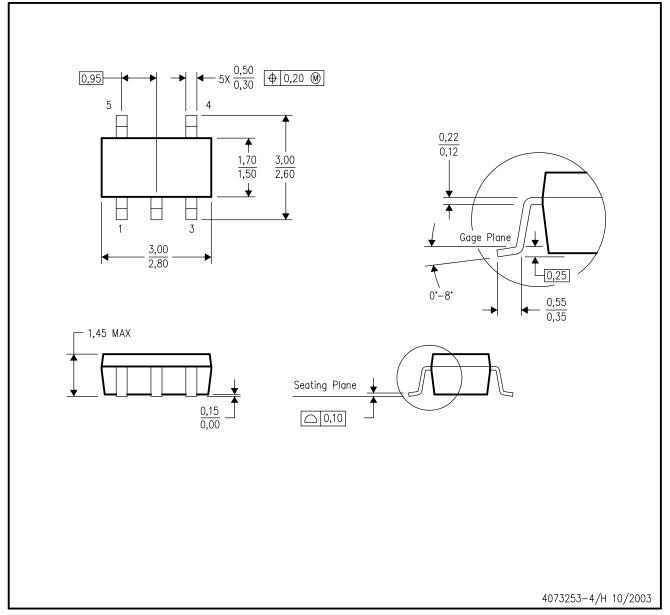


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE

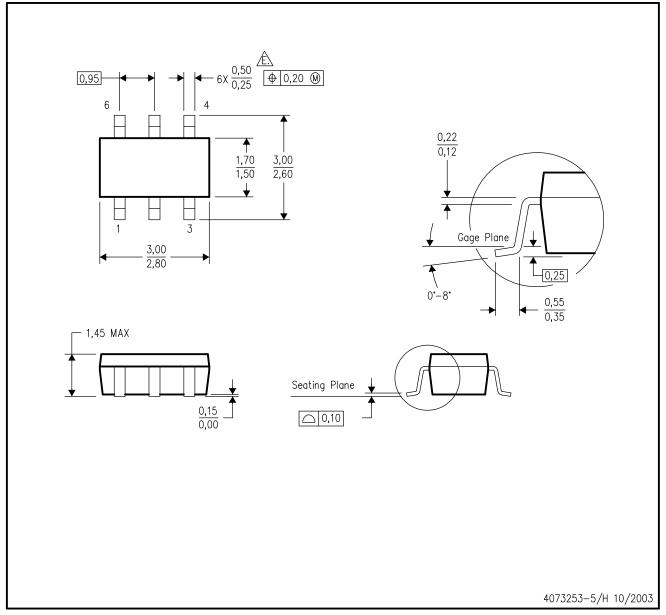


- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- C. Body dimensions do not include mold fla D. Falls within JEDEC MO—178 Variation AA. Body dimensions do not include mold flash or protrusion.



DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE

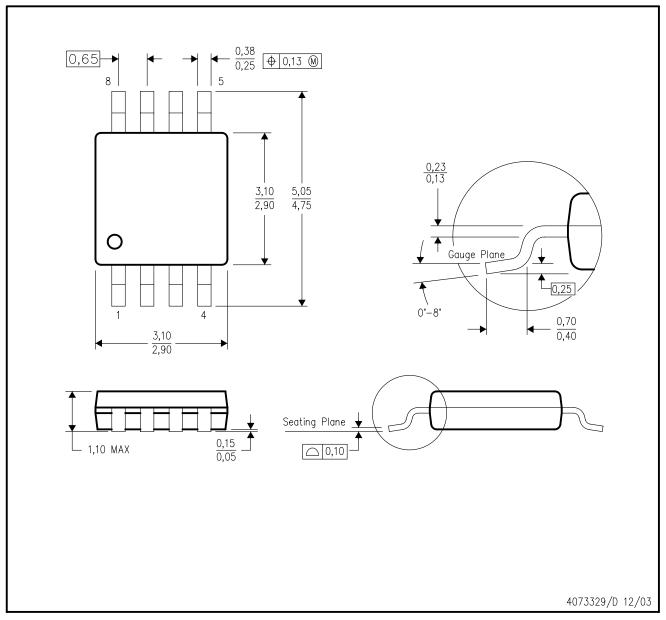


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

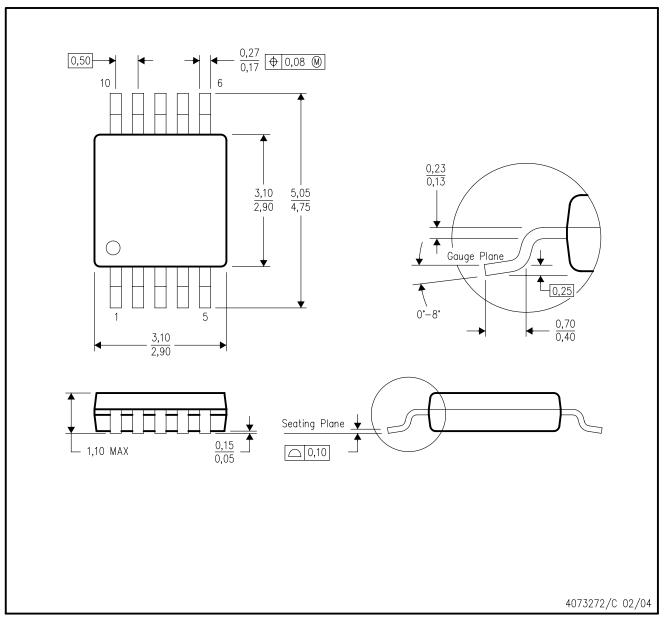


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation AA.



DGS (S-PDSO-G10)

PLASTIC SMALL-OUTLINE PACKAGE

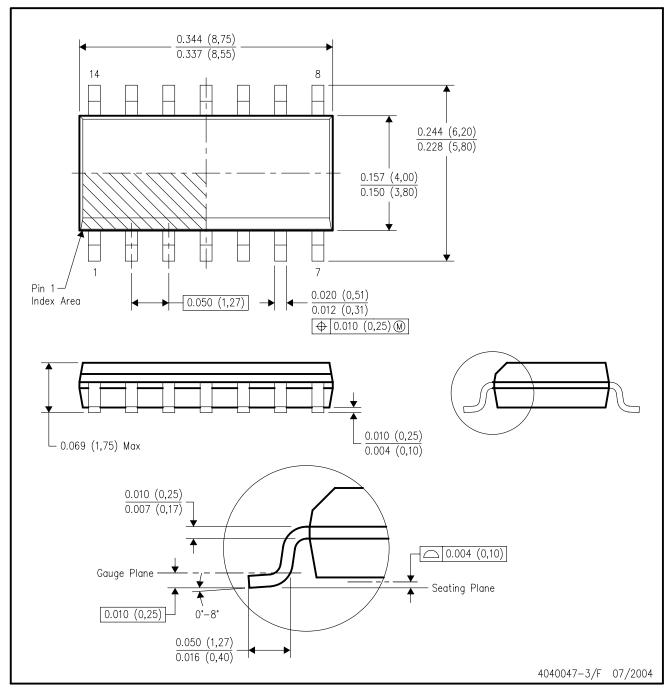


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation BA.



D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE

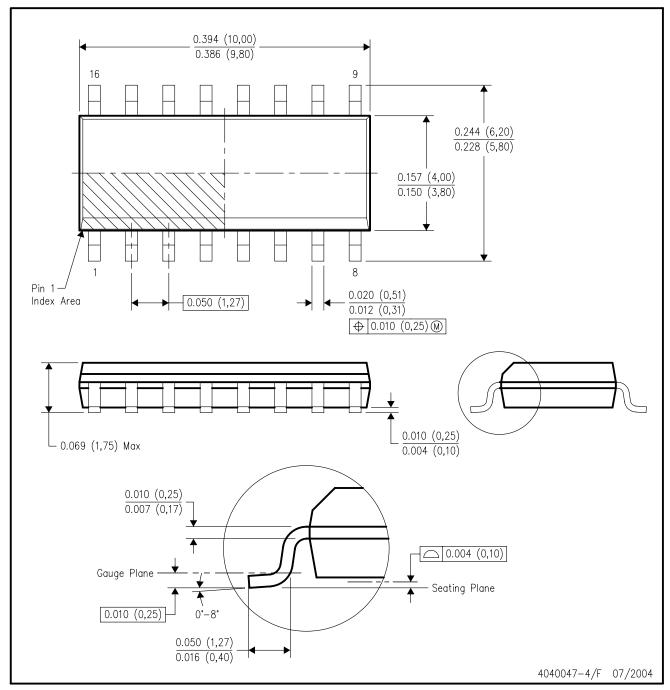


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AB.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE

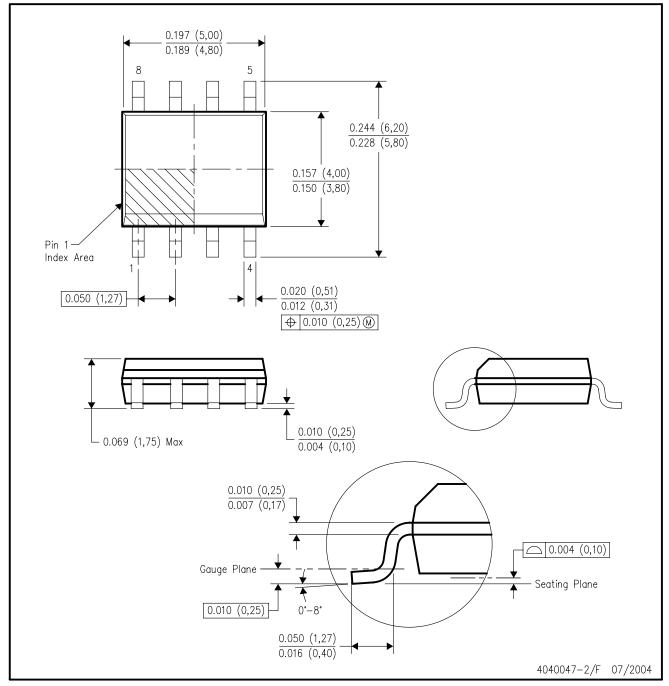


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AA.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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